

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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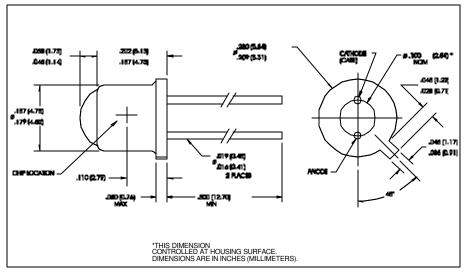






PIN Silicon Photodiode Type OP910





Features

- Narrow receiving angle
- · Fast switching time
- Linear response vs. irradiance
- Enhanced temperature range

Description

The OP910 consists of a PIN silicon photodiode mounted in a two-leaded hermetic TO-46 package. The narrow receiving angle has an acceptance half angle of $\pm 12^{\circ}$.

Ab so lute Maxi mum Rat ings ($T_A = 25^{\circ}$ C un less oth er wise noted)

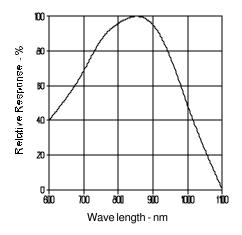
Reverse Voltage	
Storage Temperature Range	-65° C to +150° C
Operating Temperature Range	-65° C to +125° C
Lead Sol dering Temper ature [1/16 inch (1.6 mm) from case for 5 sec	
iron]	260° C ⁽¹⁾
Power Dissaipa tion	250 mW

NOTES:

- (1) RMA Flux is rec om mended. Du ra tion can be ex tended to 10 sec. max. when flow sol dering.
- (2) Light source is an un fil tered GaAlAs LED with a peak wave length of 885 nm and a radio met ric in ten sity level which var ies less than 10% over the en tire lens sur face of the pho to di ode being tested.
- (3) Junction temperature main tained at 25° C.
- 4) To cal cu late typi cal dark cur rent in nA, use. The for mual I_D = 10 (0.042 T_At-1.5) where T_A is ambient tempera ture in O C.
- (5) Der ate line arly 2.5 mw/° C above 25° C.

Typical Performance Curves

Typi cal Spec tral Re sponse

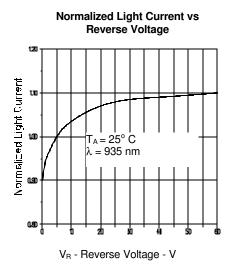


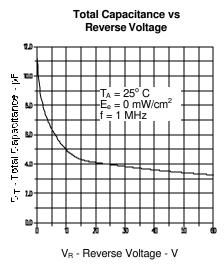
Type OP910

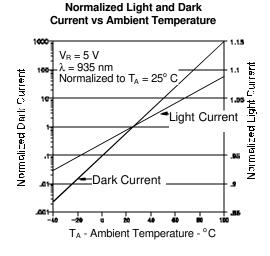
Electrical Characteristics (T_A = 25° C un less oth er wise noted)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
ΙL	Light Current	10	13		μΑ	$V_R = 20 \text{ V}, E_e = .50 \text{ mW/cm}^2 \text{ note}$ 2,3
I_{D}	Dark Current		1	10	nA	$V_R = 20 \ V, \ E_e = 0.0$
$V_{(BR)R}$	Reverse Voltage Breakdown	100			>	$I_R = 100 \mu\text{A}$
t _r	Rise Time		10		nS	$V_R = 20 \text{ V}, R_L = 50 \text{ OHMS}$
tf	Fall Time		10		nS	$V_R = 20 \text{ V}, R_L = 50 \text{ OHMS}$
Ø	Half Angle		+/- 12		degr.	I _F = Constant
CP	Capacitance		13		pF	$V_R = 0 V, F = 1 Mhz, E_e = 0$

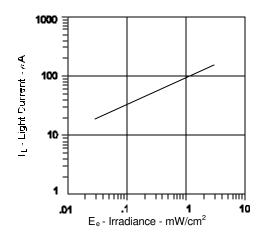
Typical Performance Curves







Light Current vs Irradiance



Switching Time Test Circuit

